

# CHEMORESISTIVE GAS SENSOR BASED ON THIN POLYANILINE FILM P. Kunzo, P. Lobotka, E. Kováčová

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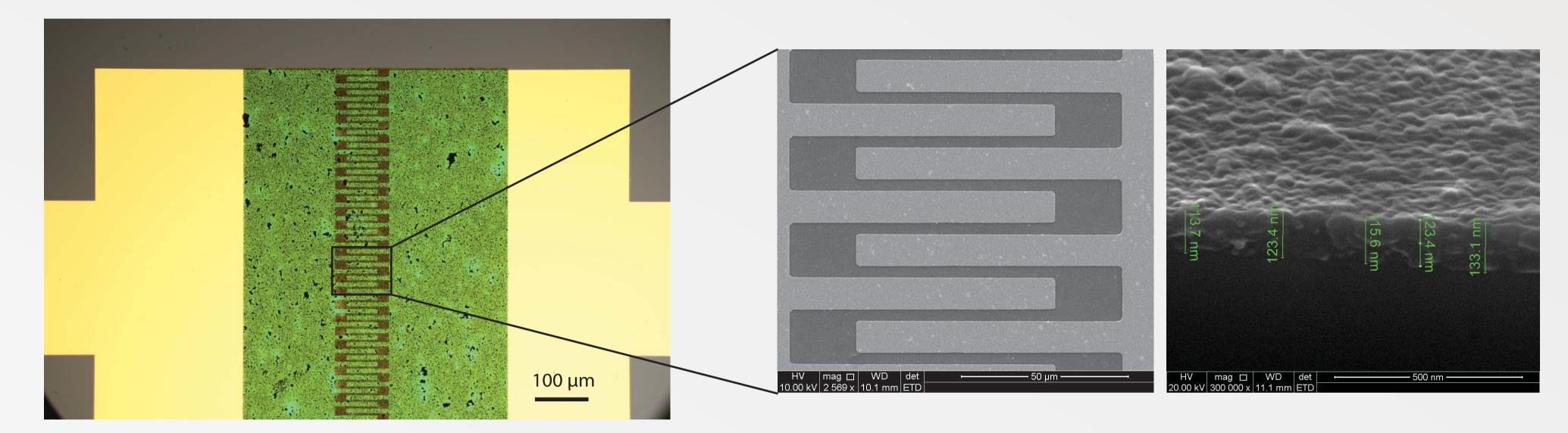
## Motivation:

Sensing of gaseous **ammonia** is critical in many environmental, agricultural, industrial, and medical applications. Concentrations as low as few ppb need to be detected. Sensitive **hydrogen** sensors are requested too, especially for fuel cell safety, facility monitoring, etc. Organic materials, such as intrinsically conducting polymers have been proposed for low-cost and high-performance gas-sensing devices. Conducting polymer-based chemoresistive gas sensors **can operate at room temperature**, which implies much lower power requirements compared with common metal-oxide sensors working usually at temperature from 200 to 400 °C. **Polyaniline (PANI)** is one of the most important conducting polymers due to its high conductivity, stability and easy preparation.

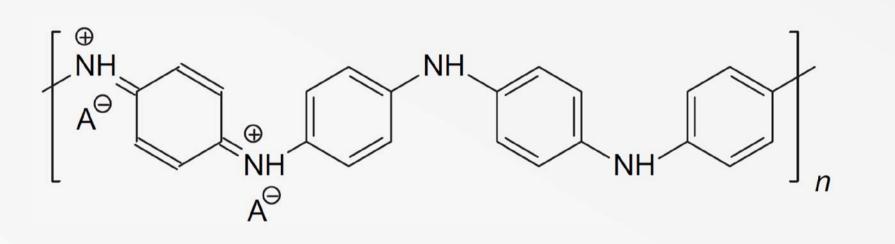
## **Experimental details:**

PANI was prepared in wet process by insitu chemical polymerization of aniline hydrochloride in presence of ammonium persulfate oxidant. Thin PANI film was deposited on the surface of gold interdigitated electrodes on the oxidized silicon substrate. Common lift-off process was used to pattern thin PANI layer. Lift-off process is supported by good adhesion of PANI to gold and silica surfaces. Both the substrate and the electrodes are evenly covered by the thin PANI film. To investigate gas sensing properties of PANI film, the sensor was exposed to different concentrations of **ammonia and** hydrogen and corresponding variations

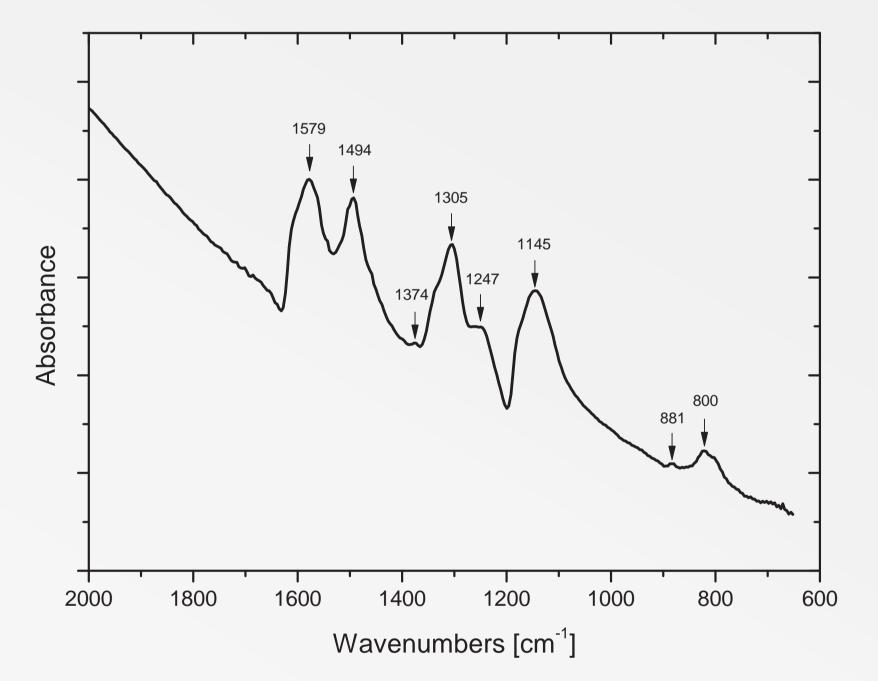
### **Results:**



Optical micrograph of lift-off patterned thin PANI film (green color) on the top of gold interdigitated electrodes.

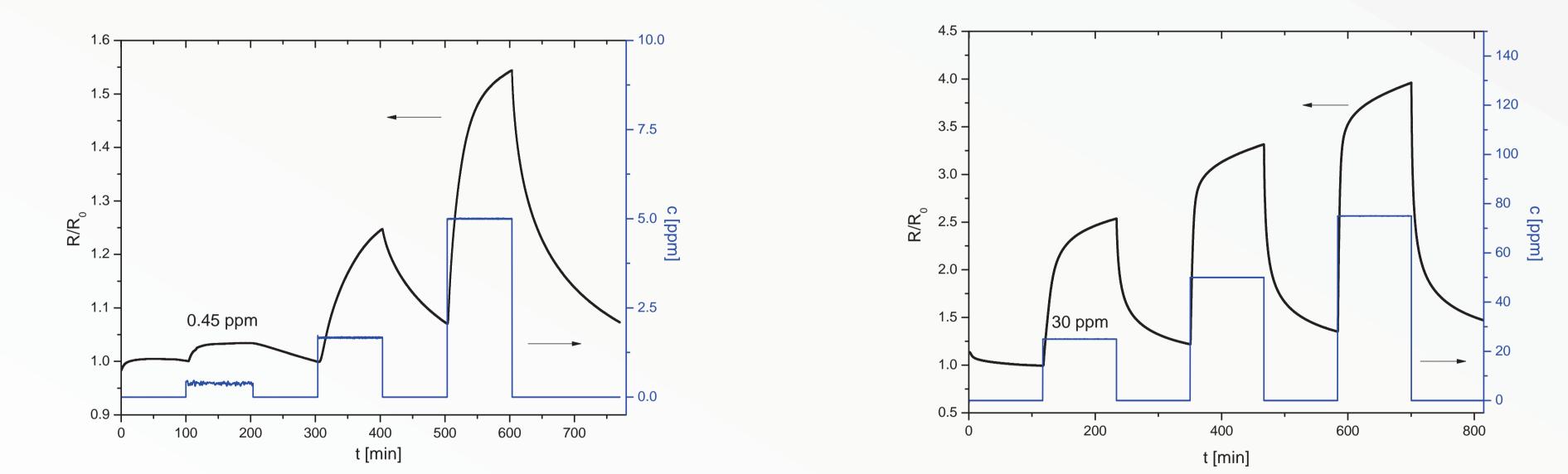


SEM micrographs of smooth thin PANI film with thickness arround 100 nm.



## of electrical resistance were recorded.

Chcemical structure of protonated polyaniline (emeraldine salt).

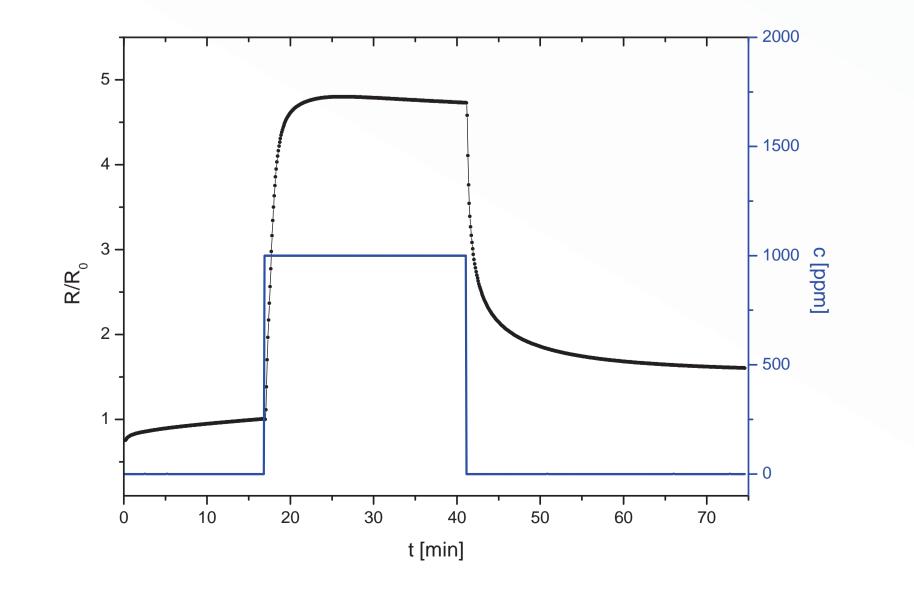


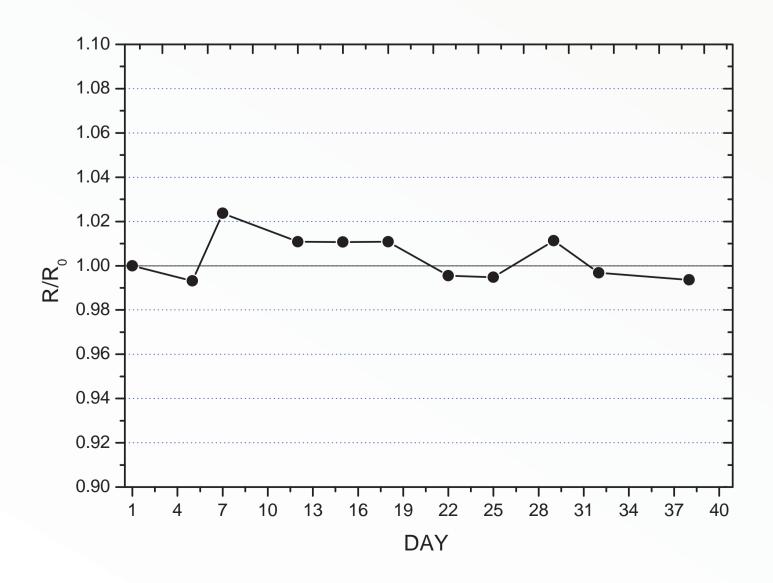
Resistance changes of thin PANI film when exposed to various concentrations of gaseous **ammonia**. Detection limit of the sensor is in the ppb range.

Infrared spectrum of thin PANI film obtained by reflection FTIR microscope. The spectrum indicates well-protonated conducting form of PANI film.

## **Conclusion:**

We found very good sensitivity of the gas sensor based on thin PANI film. The detection limits for ammonia and hydrogen were in the range of hundreds of ppb and tens of ppm respectively. Additionaly, common lift-off process can be used to successfully pattern thin and homogenous PANI film prepared in-situ.





Resistance changes of PANI film decorated by Pd particles upon the exposure to 1000 ppm of **hydrogen** gas.

**Long-term stability** of baseline resistance of thin PANI film. Data were collected at 310 K and pressure of 10-3 Pa.

#### **References:**

P. Lobotka et al.: Thin Solid Films 519 (2011) 4123
I. Šeděnková et al.: Polymer Degradation and Stability 93 (2008) 428

Acknowledgement:

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